

# ZXTP25100BFH

## 100V, SOT23, PNP medium power transistor

### Summary

$BV_{(BR)CEX} > -140V$ ,  $BV_{(BR)CEO} > -100V$

$BV_{(BR)ECX} > -7V$  ;

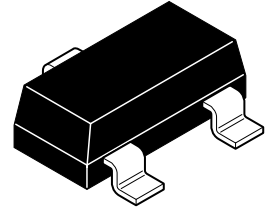
$I_{C(cont)} = -2A$

$V_{CE(sat)} < -130mV @ -1A$

$R_{CE(sat)} = 108m\Omega$  typical

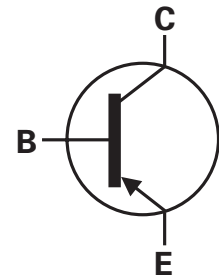
$P_D = 1.25W$

Complementary part number ZXTN25100BFH



### Description

Advanced process capability and package design have been used to maximize the power handling and performance of this small outline transistor. The compact size and ratings of this device make it ideally suited to applications where space is at a premium.

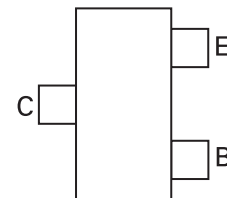


### Features

- High power dissipation SOT23 package
- High peak current
- Low saturation voltage
- 140V forward blocking voltage
- 7V reverse blocking voltage

### Applications

- MOSFET and IGBT gate driving
- DC - DC converters
- Motor drive
- Relay, lamp, and solenoid drive



Pinout - top view

### Ordering information

Device	Reel size (inches)	Tape width	Quantity per reel
ZXTP25100BFHTA	7	8mm	3,000

### Device marking

056

# ZXTP25100BFH

## Absolute maximum ratings

Parameter	Symbol	Limit	Unit
Collector-base voltage	$V_{CBO}$	-140	V
Collector-emitter voltage (forward blocking)	$V_{CEX}$	-140	V
Collector-emitter voltage	$V_{CEO}$	-100	V
Emitter-collector voltage (reverse blocking)	$V_{ECX}$	-7	V
Emitter-base voltage	$V_{EBO}$	-7	V
Continuous collector current <sup>(b)</sup>	$I_C$	-2	A
Peak pulse current	$I_{CM}$	-5	A
Power dissipation at $T_A = 25^\circ\text{C}$ <sup>(a)</sup> Linear derating factor	$P_D$	0.73 5.84	W mW/°C
Power dissipation at $T_A = 25^\circ\text{C}$ <sup>(b)</sup> Linear derating factor	$P_D$	1.05 8.4	W mW/°C
Power dissipation at $T_A = 25^\circ\text{C}$ <sup>(c)</sup> Linear derating factor	$P_D$	1.25 9.6	W mW/°C
Power dissipation at $T_A = 25^\circ\text{C}$ <sup>(d)</sup> Linear derating factor	$P_D$	1.81 14.5	W mW/°C
Operating and storage temperature range	$T_j, T_{stg}$	-55 to 150	°C

## Thermal resistance

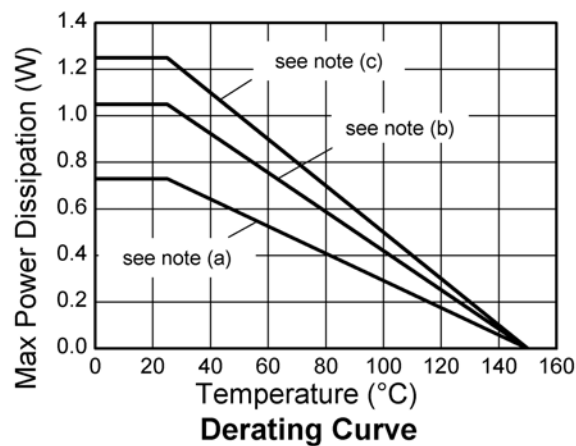
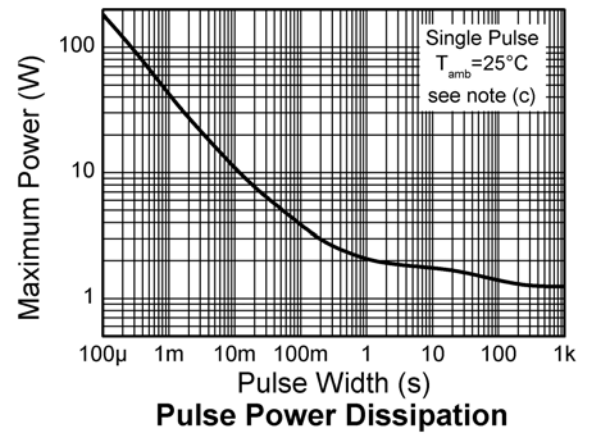
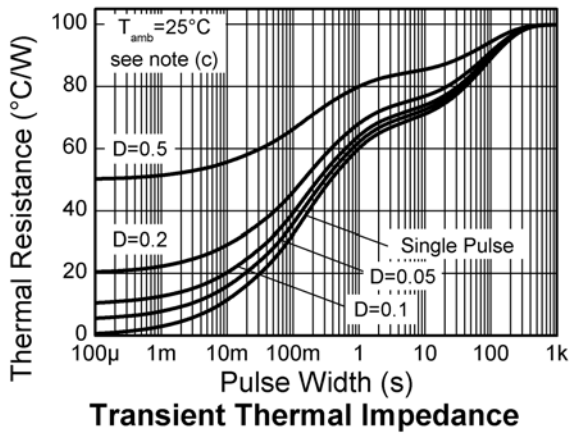
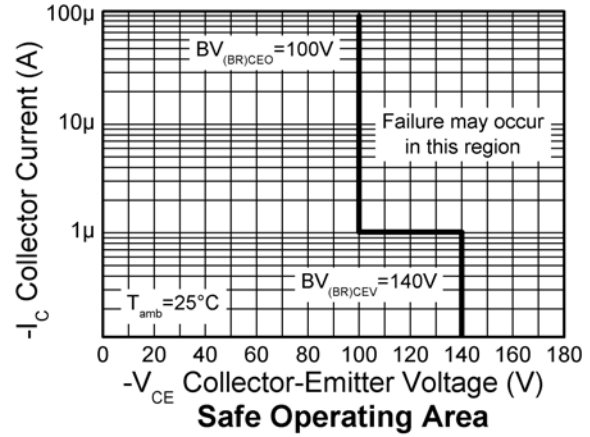
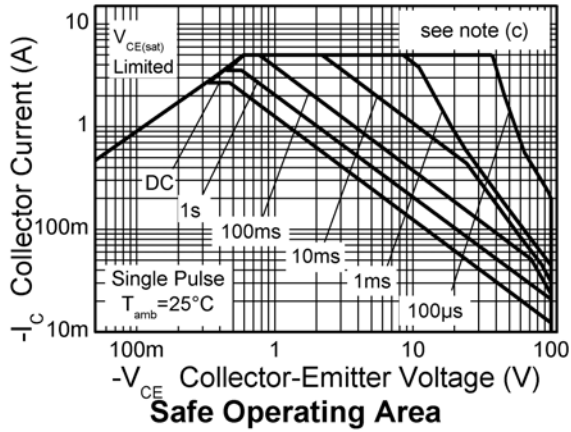
Parameter	Symbol	Limit	Unit
Junction to ambient <sup>(a)</sup>	$R_{\theta JA}$	171	°C/W
Junction to ambient <sup>(b)</sup>	$R_{\theta JA}$	119	°C/W
Junction to ambient <sup>(c)</sup>	$R_{\theta JA}$	100	°C/W
Junction to ambient <sup>(d)</sup>	$R_{\theta JA}$	69	°C/W

### NOTES:

- (a) For a device surface mounted on 15mm x 15mm x 1.6mm FR4 PCB with high coverage of single sided 1oz copper, in still air conditions.
- (b) Mounted on 25mm x 25mm x 1.6mm FR4 PCB with a high coverage of single sided 2 oz copper in still air conditions.
- (c) Mounted on 50mm x 50mm x 1.6mm FR4 PCB with a high coverage of single sided 2 oz copper in still air conditions.
- (d) As (c) above measured at  $t < 5\text{secs}$ .

# ZXTP25100BFH

## Characteristics



# ZXTP25100BFH

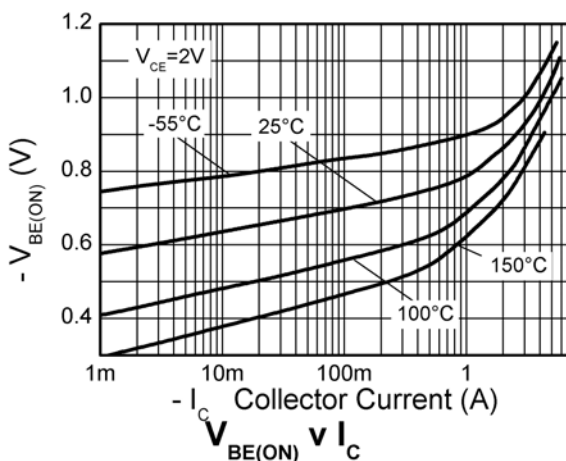
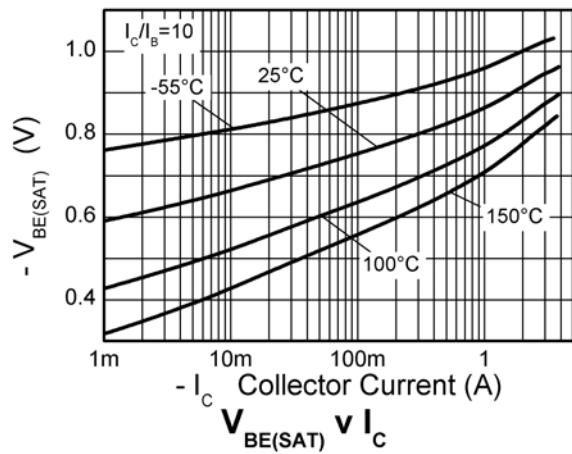
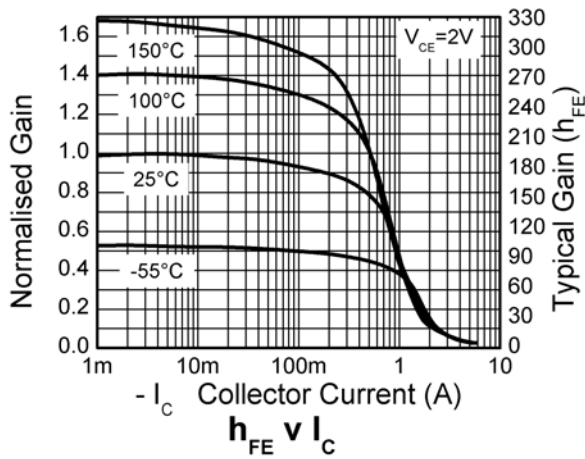
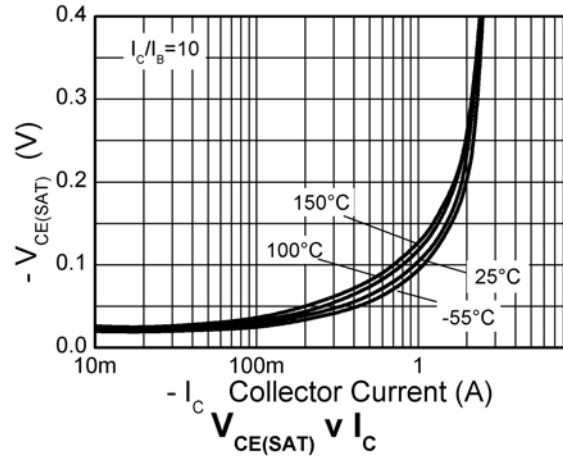
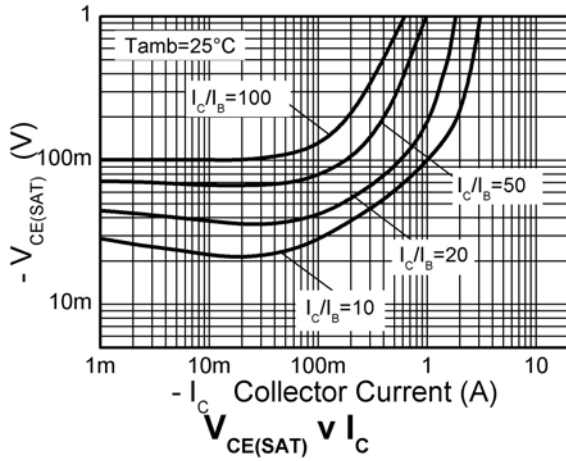
## Electrical characteristics (at $T_{AMB} = 25^{\circ}\text{C}$ unless otherwise stated)

Parameter	Symbol	Min.	Typ.	Max.	Unit	Conditions
Collector-base breakdown voltage	$BV_{CBO}$	-140	-165		V	$I_C = -100\mu\text{A}$
Collector-emitter breakdown voltage (forward blocking)	$BV_{CEX}$	-140	-165		V	$I_C = -100\mu\text{A}$ , $R_{BE} < 1\text{k}\Omega$ or $-0.25\text{V} < V_{BE} < 1\text{V}$
Collector-emitter breakdown voltage (base open)	$BV_{CEO}$	-100	-125		V	$I_C = -10\text{mA}^{(*)}$
Emitter-collector breakdown voltage (reverse blocking)	$BV_{ECX}$	-7	8.2		V	$I_E = -100\mu\text{A}$ , $R_{BC} < 1\text{k}\Omega$ or $-0.25\text{V} < V_{BC} < 0.25\text{V}$
Emitter-base breakdown voltage	$BV_{EBO}$	-7	-8.2		V	$I_E = -100\mu\text{A}$
Collector cut-off current	$I_{CBO}$		<-1	-50 -20	nA $\mu\text{A}$	$V_{CB} = -112\text{V}$ $V_{CB} = -112\text{V}$ , $T_{AMB} = 100^{\circ}\text{C}$
Collector emitter cut-off current	$I_{CEX}$		-	-100	nA	$V_{CE} = -112\text{V}$ ; $R_{BE} < 1\text{k}\Omega$ or $-0.25\text{V} < V_{BE} < 1\text{V}$
Emitter cut-off current	$I_{EBO}$		<-1	-50	nA	$V_{EB} = -5.6\text{V}$
Collector-emitter saturation voltage	$V_{CE(sat)}$		-60	-90	mV	$I_C = -0.5\text{A}$ , $I_B = -50\text{mA}^{(*)}$
			-240	-350	mV	$I_C = -0.5\text{A}$ , $I_B = -10\text{mA}^{(*)}$
			-100	-130	mV	$I_C = -1\text{A}$ , $I_B = -100\text{mA}^{(*)}$
			-215	-295	mV	$I_C = -2\text{A}$ , $I_B = -200\text{mA}^{(*)}$
Base-emitter saturation voltage	$V_{BE(sat)}$		-900	-1000	mV	$I_C = -2\text{A}$ , $I_B = -200\text{mA}^{(*)}$
Base-emitter turn-on voltage	$V_{BE(on)}$		-830	-950	mV	$I_C = -2\text{A}$ , $V_{CE} = -2\text{V}^{(*)}$
Static forward current transfer ratio	$h_{FE}$	100	200	300		$I_C = -10\text{mA}$ , $V_{CE} = -2\text{V}^{(*)}$
		55	105			$I_C = -1\text{A}$ , $V_{CE} = -2\text{V}^{(*)}$
		15	25			$I_C = -2\text{A}$ , $V_{CE} = -2\text{V}^{(*)}$
Transition frequency	$f_T$		200		MHz	$I_C = -100\text{mA}$ , $V_{CE} = -5\text{V}$ $f = 100\text{MHz}$
Output capacitance	$C_{OBO}$		15	25	pF	$V_{CB} = -10\text{V}$ , $f = 1\text{MHz}^{(*)}$
Turn-on time	$t_{(on)}$		31		ns	$V_{CC} = -10\text{V}$ , $I_C = -500\text{mA}$ ,
Turn-off time	$t_{(off)}$		384		ns	$I_{B1} = I_{B2} = -50\text{mA}$

### NOTES:

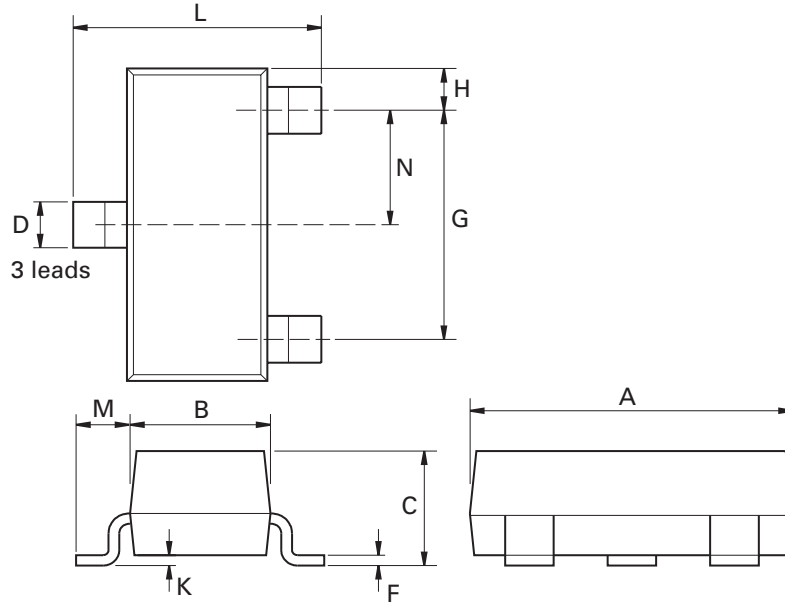
(\*) Measured under pulsed conditions. Pulse width  $\leq 300\mu\text{s}$ ; duty cycle  $\leq 2\%$ .

## Typical characteristics



# ZXTP25100BFH

## Package outline - SOT23



Dim.	Millimeters		Inches		Dim.	Millimeters		Inches	
	Min.	Max.	Min.	Max.		Min.	Max.	Max.	Max.
A	2.67	3.05	0.105	0.120	H	0.33	0.51	0.013	0.020
B	1.20	1.40	0.047	0.055	K	0.01	0.10	0.0004	0.004
C	-	1.10	-	0.043	L	2.10	2.50	0.083	0.0985
D	0.37	0.53	0.015	0.021	M	0.45	0.64	0.018	0.025
F	0.085	0.15	0.0034	0.0059	N	0.95 NOM		0.0375 NOM	
G	1.90 NOM		0.075 NOM		-	-	-	-	-

**Note:** Controlling dimensions are in millimeters. Approximate dimensions are provided in inches

Europe	Americas	Asia Pacific	Corporate Headquarters
Zetex GmbH Streitfeldstraße 19 D-81673 München Germany	Zetex Inc 700 Veterans Memorial Highway Hauppauge, NY 11788 USA	Zetex (Asia Ltd) 3701-04 Metroplaza Tower 1 Hing Fong Road, Kwai Fong Hong Kong	Zetex Semiconductors plc Zetex Technology Park, Chadderton Oldham, OL9 9LL United Kingdom
Telefon: (49) 89 45 49 49 0 Fax: (49) 89 45 49 49 49 europe.sales@zetex.com	Telephone: (1) 631 360 2222 Fax: (1) 631 360 8222 usa.sales@zetex.com	Telephone: (852) 26100 611 Fax: (852) 24250 494 asia.sales@zetex.com	Telephone: (44) 161 622 4444 Fax: (44) 161 622 4446 hq@zetex.com

For international sales offices visit [www.zetex.com/offices](http://www.zetex.com/offices)

Zetex products are distributed worldwide. For details, see [www.zetex.com/salesnetwork](http://www.zetex.com/salesnetwork)

This publication is issued to provide outline information only which (unless agreed by the company in writing) may not be used, applied or reproduced for any purpose or form part of any order or contact or be regarded as a representation relating to the products or services concerned. The company reserves the right to alter without notice the specification, design, price or conditions of supply of any product or service.

Компания «Life Electronics» занимается поставками электронных компонентов импортного и отечественного производства от производителей и со складов крупных дистрибьюторов Европы, Америки и Азии.

С конца 2013 года компания активно расширяет линейку поставок компонентов по направлению коаксиальный кабель, кварцевые генераторы и конденсаторы (керамические, пленочные, электролитические), за счёт заключения дистрибьюторских договоров

Мы предлагаем:

- Конкурентоспособные цены и скидки постоянным клиентам.
- Специальные условия для постоянных клиентов.
- Подбор аналогов.
- Поставку компонентов в любых объемах, удовлетворяющих вашим потребностям.
- Приемлемые сроки поставки, возможна ускоренная поставка.
- Доставку товара в любую точку России и стран СНГ.
- Комплексную поставку.
- Работу по проектам и поставку образцов.
- Формирование склада под заказчика.
- Сертификаты соответствия на поставляемую продукцию (по желанию клиента).
- Тестирование поставляемой продукции.
- Поставку компонентов, требующих военную и космическую приемку.
- Входной контроль качества.
- Наличие сертификата ISO.

В составе нашей компании организован Конструкторский отдел, призванный помогать разработчикам, и инженерам.

Конструкторский отдел помогает осуществить:

- Регистрацию проекта у производителя компонентов.
- Техническую поддержку проекта.
- Защиту от снятия компонента с производства.
- Оценку стоимости проекта по компонентам.
- Изготовление тестовой платы монтаж и пусконаладочные работы.



Тел: +7 (812) 336 43 04 (многоканальный)  
Email: [org@lifeelectronics.ru](mailto:org@lifeelectronics.ru)